

# HSMBJSAC5.0 thru HSMBJSAC75, e3

# 500 WATT LOW CAPACITANCE TRANSIENT VOLTAGE SUPPRESSOR

### **DESCRIPTION**

The HSMBJSAC transient voltage suppressor (TVS) series rated at 500 Watts provides an added rectifier element as shown in Figure 4 to achieve low capacitance in applications for data or signal lines. The low capacitance rating of less than 30 pF may be used for protecting higher frequency applications in inductive switching environments or electrical systems involving secondary lightning effects per IEC61000-4-5 as well as RTCA/DO-160D or ARINC 429 for airborne avionics. If bidirectional protection is needed, two HSMBJSAC devices in anti-parallel configuration are required as shown in Figure 6. With their very fast response time, they also provide ESD and EFT protection per IEC61000-4-2 and IEC61000-4-4 respectively.

### **APPEARANCE**



DO-214AA See package notes

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

#### **FEATURES**

- Unidirectional low-capacitance TVS series (for bidirectional see Figure 6)
- Suppresses transient up to 500 Watts Peak Pulse Power @ 10/1000 μs
- Improved performance in low capacitance of 30 pF
- Economical small plastic surface mount with robust axial subassembly package
- Optional 100% screening for avionics grade is available by adding MA prefix to part number for added 100% temperature cycle -55°C to +125°C (10X) as well as surge (3X) and 24 hours HTRB with post test V<sub>Z</sub> & I<sub>R</sub>
- Options for screening in accordance with MIL-PRF-19500 for JAN, JANTX, and JANTXV are also available by adding MQ, MX, or MV prefixes respectively to part number, e.g. MXHSMBJSAC5.0, MVHSMBJSAC18, etc.
- Moisture classification is Level 1 with no dry pack required per IPC/JEDEC J-STD-020B
- Also available in axial-leaded packages with part numbers (SAC5.0 thru SAC50)
- RoHS Compliant devices available by adding "e3" suffix

# MAXIMUM RATINGS

- Peak Pulse Power Dissipation at 25°C: 500 Watts @ 10/1000 μs with repetition rate of 0.01% or less\*
- Steady State Power Dissipation\*: 2.5 Watts @ T<sub>L</sub> =+75°C
- Clamping Speed (0 volts to V<sub>(BR)</sub> Min.) less than 5 nanoseconds.
- Operating and Storage Temperature: -65°C to +150°C
- Solder temperatures: 260°C for 10 s maximum

# **APPLICATIONS / BENEFITS**

- Low Capacitance for data-line protection to 10 MHz
- Protection for aircraft fast data rate lines per select waveforms in RTCA/DO-160D (see MicroNote 130 for Waveform 4 and 5A capability) & ARINC 429 with bit rates of 100 kb/s (per ARINC 429, Part 1, par. 2.4.1.1)
- ESD and EFT protection per IEC61000-4-2 and IEC61000-4-4 respectively
- Secondary lightning protection per IEC61000-4-5 with 42 Ohms source impedance:

Class 1: HSMBJSAC5.0 to HSMBJSAC75

Class 2: HSMBJSAC5.0 to HSMBJSAC45

Class 3: HSMBJSAC5.0 to HSMBJSAC22

Class 4: HSMBJSAC5.0 to HSMBJSAC10

 Secondary lightning protection per IEC61000-4-5 with 12 Ohms source impedance

Class 1: HSMBJSAC5.0 to HSMBJSAC26

Class 2: HSMBJSAC5.0 to HSMBJSAC15

Class 3: HSMBJSAC5.0 to HSMBJSAC7.0

#### **MECHANICAL AND PACKAGING**

- CASE: Void Free Transfer Molded Thermosetting Plastic package meeting UL94V-0
- FINISH: Tin-Lead or RoHS Compliant matte-Tin plating solderable per MIL-STD-750, method 2026
- POLARITY: Cathode (TVS) Marked with Band
- MARKING: Part number without HSMBJ prefix (ie. SAC5.0, SAC5.0e3, etc)
- WEIGHT: 0.1 Grams (Approx.)
- See package dimensions on last page
- \* TVS devices are not typically used for dc power dissipation and are instead operated ≤ V<sub>WM</sub> (rated standoff voltage) except for transients that briefly drive the device into avalanche breakdown (V<sub>BR</sub> to V<sub>C</sub> region) of the TVS element. Also see Figures 5 and 6 for further protection details in rated peak pulse power for unidirectional and bidirectional configurations respectively.

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	DEVEDOE	DDE AKDOMAL	BA A VIBALIBA	BA A VIBALIBA	NA A VINALINA	MANURALINA	WORKING	INIVEROE	DEAK
MICROSEMI	REVERSE STAND-OFF	BREAKDOWN VOLTAGE	MAXIMUM STANDBY	MAXIMUM CLAMPING	MAXIMUM PEAK PULSE	MAXIMUM CAPACITANCE	WORKING INVERSE	INVERSE BLOCKING	PEAK INVERSE
PART NUMBER	VOLTAGE	@ I <sub>(BR)</sub> 1.0mA	CURRENT	VOLTAGE	CURRENT*	@ O Volts,	BLOCKING	LEAKAGE	BLOCKING
I AIT HOMBER	(Note 1)	, ,	@V <sub>WM</sub>	I <sub>P</sub> = 5.0A*	RATING	f=1 MHz	VOLTAGE	CURRENT	VOLTAGE
	V <sub>WM</sub>	$V_{(BR)}$		V <sub>C</sub>	I <sub>PP</sub>		V <sub>WIB</sub>	I <sub>IB</sub> @ V <sub>WIB</sub>	V <sub>PIB</sub>
	V VVIVI	Volts	I <sub>D</sub>	v.C	iPP		* WID	IB © VWIB	V PIB
	Volts	Min.	μА	Volts	Amps	pF	Volts	μΑ	Volts
HSMBJSAC5.0	5.0	7.60	300	10.0	44	30	75	10	100
HSMBJSAC6.0	6.0	7.90	300	11.2	41	30	75	10	100
HSMBJSAC7.0	7.0	8.33	300	12.6	38	30	75	10	100
HSMBJSAC8.0	8.0	8.89	100	13.4	36	30	75	10	100
HSMBJSAC8.5	8.5	9.44	50	14.0	34	30	75	10	100
HSMBJSAC10	10	11.10	5.0	16.3	29	30	75	10	100
HSMBJSAC12	12	13.30	5.0	19.0	25	30	75	10	100
HSMBJSAC15	15	16.70	5.0	23.6	20	30	75	10	100
HSMBJSAC18	18	20.00	5.0	28.8	15	30	75	10	100
HSMBJSAC22	22	24.40	5.0	35.4	14	30	75	10	100
HSMBJSAC26	26	28.90	5.0	42.3	11.1	30	75	10	100
HSMBJSAC36	36	40.0	5.0	60.0	8.6	30	75	10	100
HSMBJSAC45	45	50.00	5.0	77.0	6.8	30	150	10	200
HSMBJSAC50	50	55.50	5.0	88.0	5.8	30	150	10	200
HSMBJSAC75	75	83.3	5.0	121	4.1	30	150	10	200

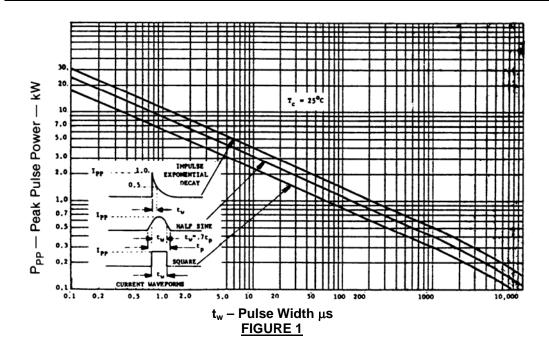
\*See Figure 3. For the HSMBJSAC75, the maximum clamping voltage V<sub>C</sub> is at the maximum rated Peak Pulse Current (I<sub>PP</sub>) of 4.1 Amps.

Clamping Factor: The ratio of the numerical value of V<sub>C</sub> to V<sub>(BR)</sub> is typically 1.4 @ full rated power, 1.20 @ 50% rated power. Also see MicroNote 108.

Note 1: A transient voltage suppressor is normally selected according to voltage (V<sub>WM</sub>), that should be equal to or greater than the dc or continuous peak operating voltage level.

Note 2: When pulse testing, test in TVS avalanche direction. Do not pulse in "forward" direction. See section for "Schematic Applications" herein.

# **GRAPHS**

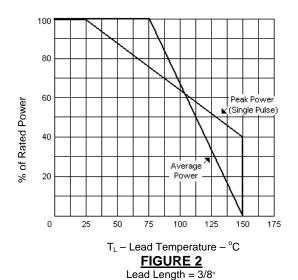


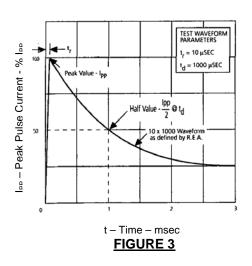
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### **SCHEMATIC APPLICATIONS**

The TVS low capacitance device configuration is shown in Figure 4. As a further option for unidirectional applications, an additional low capacitance rectifier diode may be used in parallel in the same polarity direction as the TVS as shown in Figure 5. In applications where random high voltage transients occur, this will prevent reverse transients from damaging the internal low capacitance rectifier diode and also provide a low voltage conducting direction. The added rectifier diode should be of similar low capacitance and also have a higher reverse voltage rating than the TVS clamping voltage  $V_c$ . The Microsemi recommended rectifier part number is the "HSMBJLCR60" for the application in Figure 5. If using two (2) low capacitance TVS devices in anti-parallel for bidirectional applications, this added protective feature for both directions (including the reverse of each rectifier diode) is inherently provided in Figure 6. The unidirectional and bidirectional configurations in Figure 5 and 6 will both result in twice the capacitance of Figure 4.

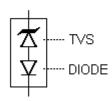


FIGURE 4
TVS with internal Low
Capacitance Diode

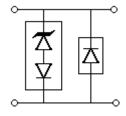
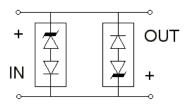
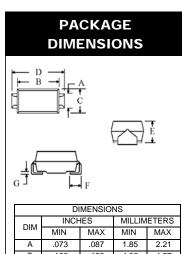


FIGURE 5
Optional Unidirectional configuration (TVS and separate rectifier diode) in parallel)



**FIGURE 6** Optional Bidirectional configuration (two TVS devices in anti-parallel)



DIM	INCH	HES	MILLIMETERS						
DIIVI	MIN	MAX	MIN	MAX					
Α	.073	.087	1.85	2.21					
В	.160	.180	4.06	4.57					
С	.130	.155	3.30	3.94					
D	.205	.220	5.21	5.59					
Е	.075	.130	1.91	3.30					
F	.030	.060	.76	1.52					
G	.006	.016	.15	.41					
NOTE: Dimension E exceeds the									

NOTE: Dimension E exceeds the JEDEC outline in height as shown

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